

NJT4030PT1G

Data Sheet

NJT Series 40 V 3 A Surface Mount PNP Silicon Power Transistor - SOT-223

Manufacturers

ON Semiconductor, LLC

Package/Case

SOT-223

Product Type

Transistors

RoHS Pb-free Halide free

Lifecycle



Images are for reference only

Please submit RFQ for NJT4030PT1G or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

The combination of low saturation voltage and high gain makes this bipolar power transistor an ideal device for high speed switching applications where power saving is a concern.

Features Application

Low Collector-Emitter Saturation Voltage

ONSEMI

Minimized power loss

High DC Current Gain

Very low current requirements

High Current-Gain Bandwidth Product

Ideal for high frequency designs

NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AECQ101 Qualified and PPAP Capable

These Devices are PbFree, Halogen Free/BFR Free and are RoHS Compliant

Related Products

NJVMJD112G



ON Semiconductor, LLC

DPAK-3



NJVMJD45H11G

ON Semiconductor, LLC

DPAK-3

NJVMJD42CT4G



ON Semiconductor, LLC

DPAK-3



NJVMJD44H11D3T4G

ON Semiconductor, LLC

DPAK-3

NJVMJD45H11D3T4G



ON Semiconductor, LLC

DPAK-3



NJVMJD42CRLG

ON Semiconductor, LLC

DPAK-3

NJVMJD340T4G



ON Semiconductor, LLC

DPAK-2



NJVMJD127T4G

ON Semiconductor, LLC

DPAK-3